

# 50 V, 2 A PNP low VCEsat transistor

**Product data sheet** 

### 1. General description

PNP general-purpose low V<sub>CEsat</sub> transistor in a medium power SOT89 (SC-62) Surface-Mounted Device (SMD) plastic package.

NPN complement: PBSS4250X-Q

#### 2. Features and benefits

- SOT89 (SC-62) package
- Low collector-emitter saturation voltage V<sub>CEsat</sub>
- High collector current capability: I<sub>C</sub> and I<sub>CM</sub>
- · Higher efficiency leading to less heat generation
- Reduced printed-circuit board requirements
- Qualified according to AEC-Q101 and recommended for use in automotive applications

### 3. Applications

- Power management
  - DC/DC converters
  - Supply line switching
  - Battery charger
  - · LCD backlighting
- Peripheral drivers
  - Driver in low supply voltage applications (e.g. lamps and LEDs)
  - Inductive load driver (e.g. relays, buzzers and motors)

### 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	-50	V
I <sub>C</sub>	collector current		-	-	-2	Α
h <sub>FE</sub>	DC current gain	$V_{CE} = -2 \text{ V}; I_{C} = -0.1 \text{ A}; T_{amb} = 25 ^{\circ}\text{C}$	200	-	-	



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## 5. Pinning information

#### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	Е	emitter		С
2	С	collector		, , , , , , , , , , , , , , , , , , ,
3	В	base	3 2 1	B—[
			SOT89	sym132

## 6. Ordering information

#### **Table 3. Ordering information**

Type number	Package	ackage				
	Name	Description	Version			
PBSS5250X-Q		plastic, surface-mounted package; 3 leads; 1.5 mm pitch; 4.5 mm x 2.5 mm x 1.5 mm body	SOT89			

### 7. Marking

#### Table 4. Marking codes

Type number	Marking code[1]
PBSS5250X-Q	%1L

[1] % = placeholder for manufacturing site code

## 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter		-	-50	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-50	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	-5	V
I <sub>C</sub>	collector current			-	-2	Α
I <sub>CM</sub>	peak collector current	limited by T <sub>j(max)</sub>		-	-5	Α
I <sub>B</sub>	base current			-	-0.5	Α
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	550	mW
			[2]	-	1	W
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-65	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

Device mounted on an FR4 PCB, single-sided, 35 µm copper, tin-plated and standard footprint. Device mounted on an FR4 PCB, single-sided, 35 µm copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.

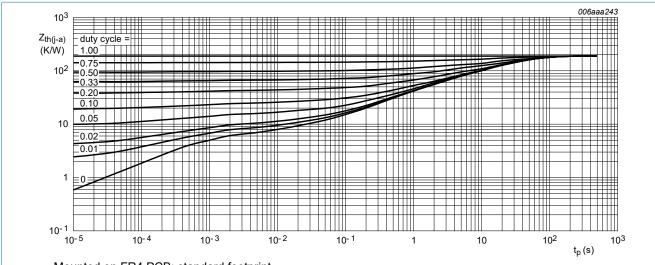
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### 9. Thermal characteristics

**Table 6. Thermal characteristics** 

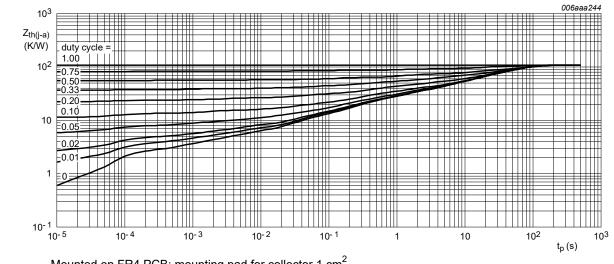
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
"'() "\")	thermal resistance from	<u> </u>	[1]	-	-	225	K/W
	junction to ambient		[2]	-	-	125	K/W
		[3]	-	-	90	K/W	
		[4	[4]	-	-	80	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	-	16	K/W

- Device mounted on an FR4 PCB, single-sided, 35  $\mu m$  copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided, 35 µm copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.
- Device mounted on an FR4 PCB, single-sided, 35 µm copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>. Device mounted on a ceramic PCB, 7 cm<sup>2</sup>, single-sided, 35 µm copper, tin-plated; standard footprint. [3]
- [4]



Mounted on FR4 PCB; standard footprint.

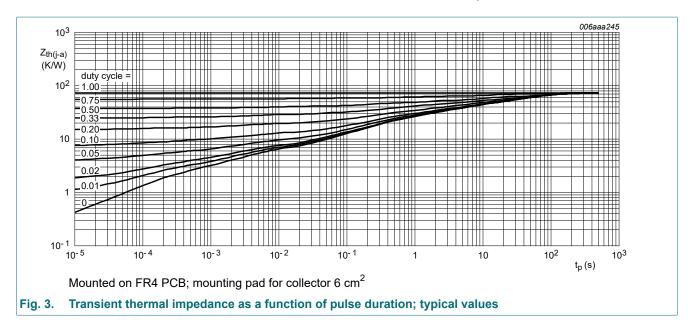
Transient thermal impedance as a function of pulse duration; typical values Fig. 1.



Mounted on FR4 PCB; mounting pad for collector 1 cm<sup>2</sup>

Transient thermal impedance as a function of pulse duration; typical values

#### 50 V, 2 A PNP low VCEsat transistor



### 10. Characteristics

**Table 7. Characteristics** 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>(BR)CBO</sub>	collector-base breakdown voltage	$I_C = -100 \ \mu A; I_E = 0 \ A; T_{amb} = 25 \ ^{\circ}C$	-50	-	-	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	$I_C = -2 \text{ mA}; I_B = 0 \text{ A}; T_{amb} = 25 \text{ °C}$	-50	-	-	V
$V_{(BR)EBO}$	emitter-base breakdown voltage	$I_E = -100 \ \mu A; I_C = 0 \ A; T_{amb} = 25 \ ^{\circ}C$	-5	-	-	V
I <sub>CBO</sub>	collector-base cut-off	V <sub>CB</sub> = -50 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	-100	nA
	current	V <sub>CB</sub> = -50 V; I <sub>E</sub> = 0 A; T <sub>j</sub> = 150 °C	-	-	-50	μA
I <sub>CES</sub>	collector-emitter cut-off current	V <sub>CE</sub> = -50 V; V <sub>BE</sub> = 0 V; T <sub>amb</sub> = 25 °C	-	-	-100	nA
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = -5 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	-100	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = -2 V; I <sub>C</sub> = -0.1 A; T <sub>amb</sub> = 25 °C	200	-	-	
		V <sub>CE</sub> = -2 V; I <sub>C</sub> = -0.5 A; T <sub>amb</sub> = 25 °C	200	-	-	
		$V_{CE}$ = -2 V; $I_{C}$ = -1 A; pulsed; $t_{p}$ ≤ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	200	-	-	
		$V_{CE}$ = -2 V; $I_{C}$ = -2 A; pulsed; $t_{p}$ ≤ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	100	-	-	
V <sub>CEsat</sub>	collector-emitter	I <sub>C</sub> = -0.5 A; I <sub>B</sub> = -50 mA; T <sub>amb</sub> = 25 °C	-	-	-90	mV
	saturation voltage	I <sub>C</sub> = -1 A; I <sub>B</sub> = -50 mA; T <sub>amb</sub> = 25 °C	-	-	-250	mV
		I <sub>C</sub> = -2 A; I <sub>B</sub> = -100 mA; T <sub>amb</sub> = 25 °C	-	-	-380	mV
		$I_C$ = -2 A; $I_B$ = -200 mA; pulsed; $t_p \le$	-	-	-320	mV
R <sub>CEsat</sub>	collector-emitter saturation resistance	300 μs; δ ≤ 0.02; T <sub>amb</sub> = 25 °C	-	-	160	mΩ
$V_{BEsat}$	base-emitter saturation voltage	$I_C = -2 \text{ A}; I_B = -100 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$	-	-	-1.1	V
$V_{BEon}$	base-emitter turn-on voltage	V <sub>CE</sub> = -2 V; I <sub>C</sub> = -1 A; T <sub>amb</sub> = 25 °C	-1.1	-	-	V

### 50 V, 2 A PNP low VCEsat transistor

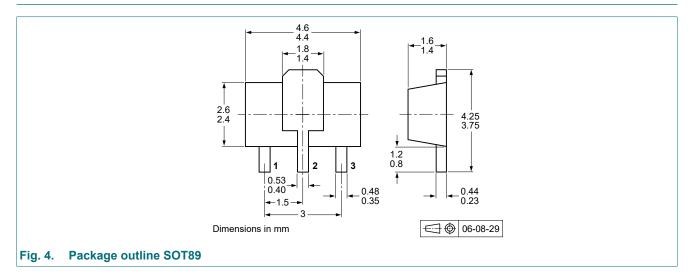
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
f <sub>T</sub>	transition frequency	$V_{CE}$ = -5 V; $I_{C}$ = -100 mA; f = 100 MHz; $T_{amb}$ = 25 °C	100	-	-	MHz
C <sub>c</sub>		$V_{CB}$ = -10 V; $I_E$ = 0 A; $i_e$ = 0 A; $f$ = 1 MHz; $T_{amb}$ = 25 °C	-	-	35	pF

## 11. Test information

### **Quality information**

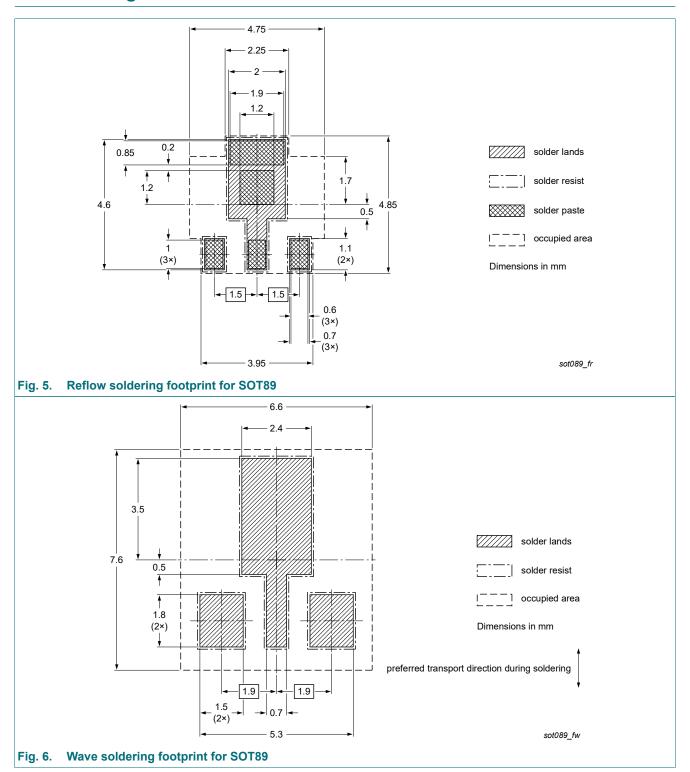
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 -Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

## 12. Package outline



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## 13. Soldering



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# 14. Revision history

#### **Table 8. Revision history**

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PBSS5250X-Q v.1	20250731	Product data sheet	-	-

### 50 V, 2 A PNP low VCEsat transistor

### 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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